

DTM1501 www.din-tek.jp

P-Channel 150 V (D-S) MOSFET

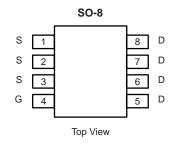
PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω) Max.	I _D (A)	Q _g (Typ.)		
	0.230 at V _{GS} = - 10 V	- 1.9			
- 150	0.295 at V_{GS} = - 7.5 V	- 1.3	12		
	0.350 at V _{GS} = - 6 V	- 1.0			

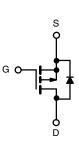
FEATURES

- Halogen-free According to IEC 61249-2-21 ٠ Definition
- TrenchFET[®] Power MOSFET ٠
- 100 % R_{α} and UIS Tested •
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- DC/DC Converters
- Motor Control





P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V _{DS}	- 150	V			
Gate-Source Voltage	V _{GS}	± 20	V			
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	I _D	- 1.9			
	T _C = 70 °C		- 1.5			
Pulsed Drain Current	I _{DM}	- 16	A			
Avalanche Current	I _{AS}	- 8				
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	8.5	mJ		
Maximum Power Dissipation ^a	T _C = 25 °C	P	21 ^b			
	T _A = 25 °C ^c	– P _D –	1.8	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	68	°C/W		
Junction-to-Case (Drain)	R _{thJC}	5.5			

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.c. When mounted on 1" square PCB (FR-4 material).



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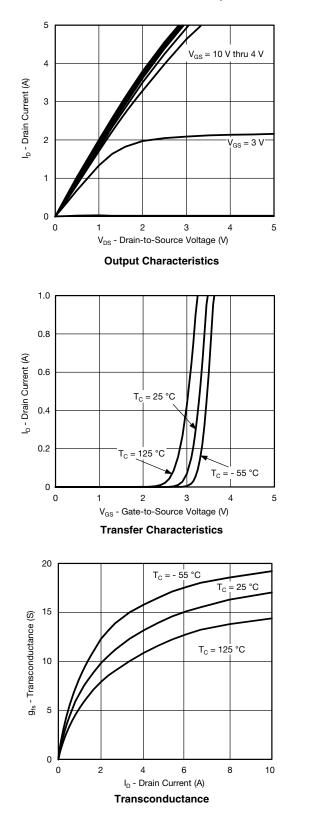
Parameter	Symbol	Symbol Test Conditions		Тур.	Max.	Unit	
Static		· · · ·					
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 V, I_{D} = -250 \mu A$	- 150			v	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1.5		- 3.0	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA	
Zero Gate Voltage Drain Current		$V_{DS} = -100 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	- 50 μA	
	I _{DSS}	V_{DS} = - 100 V, V_{GS} = 0 V, T_{J} = 125 °C			- 50		
		V_{DS} = - 100 V, V_{GS} = 0 V, T_{J} = 150 °C			- 250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \leq$ - 10 V, V_{GS} = - 10 V	- 1.9			Α	
		V _{GS} = - 10 V, I _D = - 3.6 A		0.230			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 7.5 V, I _D = - 3.5 A		0.295		Ω	
		V _{GS} = - 6 V, I _D = - 3.5 A		0.350		-	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 20 V, I _D = - 3.6 A		10		S	
Dynamic ^b				1			
Input Capacitance	C _{iss}			1088		pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = - 50 V, f = 1 MHz		158			
Reverse Transfer Capacitance	C _{rss}			69			
Tatal Cata Charge	Q _q	$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -3.6 \text{ A}$	$_{\rm S}$ = - 50 V, V _{GS} = - 10 V, I _D = - 3.6 A 30	45			
Total Gate Charge ^c	Чg			19	29	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = -50$ V, $V_{GS} = -4.5$ V, $I_{D} = -3.6$ A		5			
Gate-Drain Charge ^c	Q _{gd}			5.8			
Gate Resistance	Rg	f = 1 MHz	1.3	6.8	15	Ω	
Turn-On Delay Time ^c	t _{d(on)}			9	18		
Rise Time ^c	t _r	V_{DD} = - 50 V, R_L = 17.2 Ω		9	18	20	
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D}\cong$ - 2.9 A, V_GEN = - 10 V, R_g = 1 Ω		35	55	ns	
Fall Time ^c	t _f			16	28	1	
Drain-Source Body Diode Ratings ar	nd Character	istics T _C = 25 °C ^b					
Continuous Current	I _S				- 1.9		
Pulsed Current	I _{SM}				- 16	A	
Forward Voltage ^a	V _{SD}	I _F = - 2.9 A, V _{GS} = 0 V		- 0.88	- 1.5	V	
Reverse Recovery Time	t _{rr}			68	96	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 2.9 A, dl/dt = 100 A/μs		- 1.5	- 1.9	А	
Reverse Recovery Charge	Q _{rr}	4		186	295	nC	

Notes:

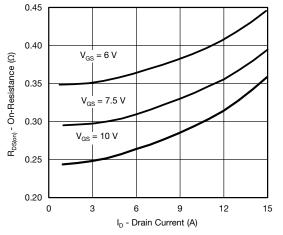
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

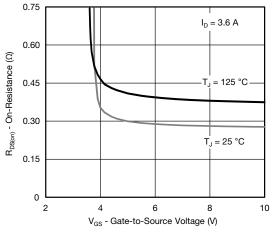




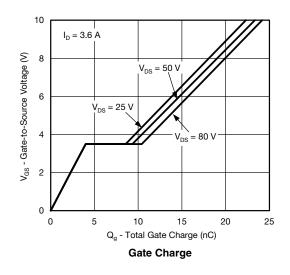
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



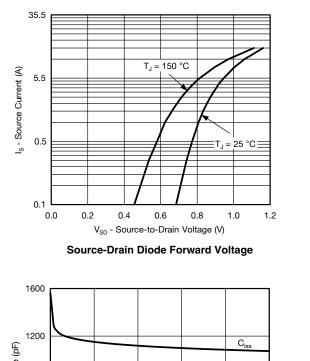
On-Resistance vs. Drain Current



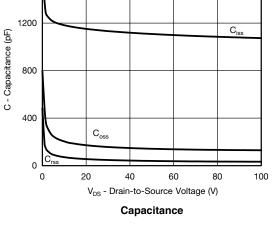
On-Resistance vs. Gate-to-Source Voltage

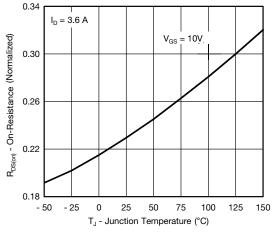




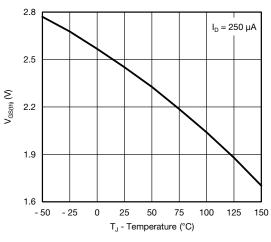


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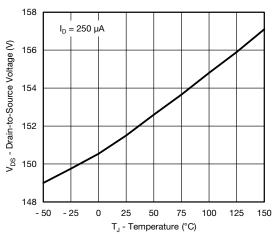




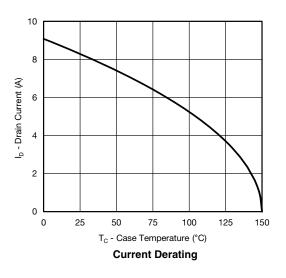
On-Resistance vs. Junction Temperature



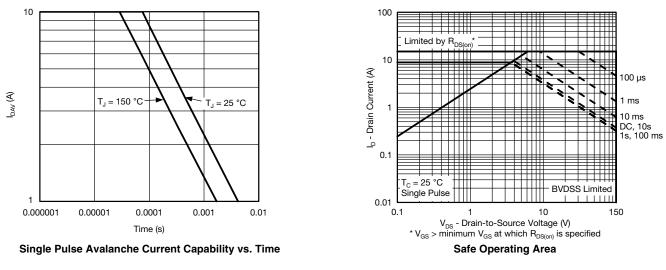
Threshold Voltage



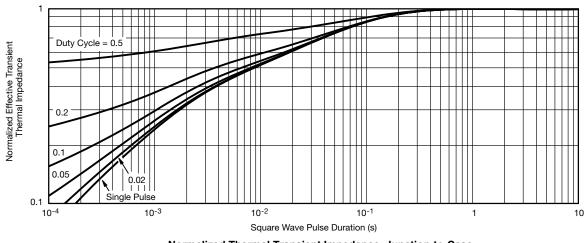
Drain Source Breakdown vs. Junction Temperature







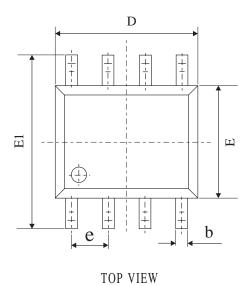
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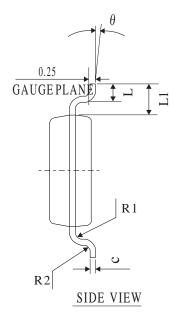


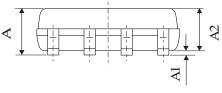
Normalized Thermal Transient Impedance, Junction-to-Case



SOP-8 PACKAGE OUTLINE







SIDE VIEW

COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	ТҮР	MAX
А	1.30	1.60	1.85
A1	0.03	0.15	0.28
A2	1.20	1.45	1.70
b	0.26	0.40	0.54
С	0.132	0.203	0.273
D	4.50	4.90	5.30
Е	3.50	3.00	4.30
E1	5.50	6.00	6.50
L	0.30	0.70	1.10
θ	2°	4°	6°
L1	1.04REF		
e	1.27BSC		
R1	0.07TYP		
R2	0.07TYP		



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